

LMR1A - LMR1M

PRV : 50 - 1000 Volts
Io : 1.0 Ampere

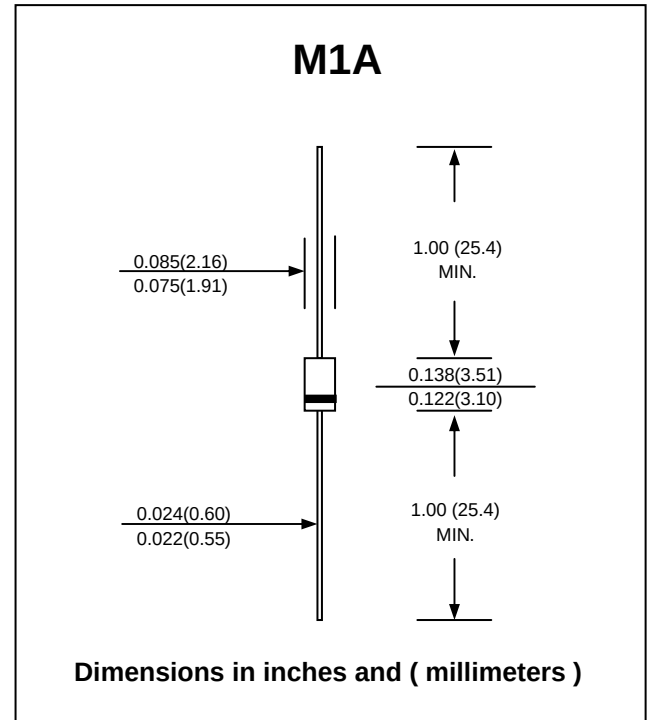
FEATURES :

- * Glass passivated junction chip
- * High surge current capability
- * High reliability
- * Low reverse current
- * Low forward voltage drop
- * Fast switching for high efficiency
- * **Pb / RoHS Free**

MECHANICAL DATA :

- * Case : M1A Molded plastic
- * Epoxy : UL94V-O rate flame retardant
- * Lead : Axial lead solderable per MIL-STD-202, Method 208 guaranteed
- * Polarity : Color band denotes cathode end
- * Mounting position : Any
- * Weight : 0.20 gram (approximately)

GLASS PASSIVATED JUNCTION FAST RECOVERY RECTIFIERS



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

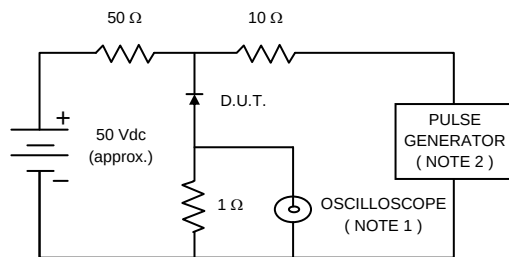
RATING	SYMBOL	LMR1A	LMR1B	LMR1D	LMR1G	LMR1J	LMR1K	LMR1M	UNIT
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Current 0.375"(9.5mm) Lead Length Ta = 55 °C	I _{F(AV)}	1.0							A
Peak Forward Surge Current, 8.3ms Single half sine wave Superimposed on rated load (JEDEC Method)	I _{FSM}	25							A
Maximum Peak Forward Voltage at IF = 1.0 Amp.	V _F	1.4							V
Maximum DC Reverse Current Ta = 25 °C	I _R	5							μA
at Rated DC Blocking Voltage Ta = 100 °C	I _{R(H)}	50							μA
Maximum Reverse Recovery Time (Note 1)	Trr	150				250	500		ns
Typical Junction Capacitance (Note 2)	C _J	50							pF
Junction Temperature Range	T _J	- 65 to + 150							°C
Storage Temperature Range	T _{STG}	- 65 to + 150							°C

Notes :

- (1) Reverse Recovery Test Conditions : $I_F = 0.5\text{ A}$, $I_R = 1.0\text{ A}$, $I_{rr} = 0.25\text{ A}$.
- (2) Measured at 1.0 MHz and applied reverse voltage of 4.0 V_{DC}

RATING AND CHARACTERISTIC CURVES (LMR1A - LMR1M)

FIG.1 - REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES : 1. Rise Time = 7 ns max., Input Impedance = 1 megaohm, 22 pF.
2. Rise time = 10 ns max., Source Impedance = 50 ohms.
3. All Resistors = Non-inductive Types.

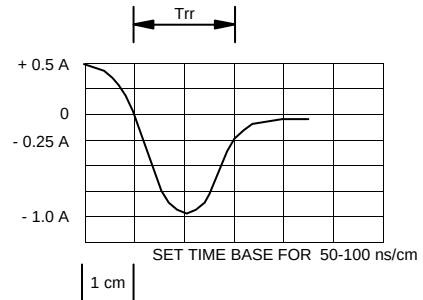


FIG.2 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

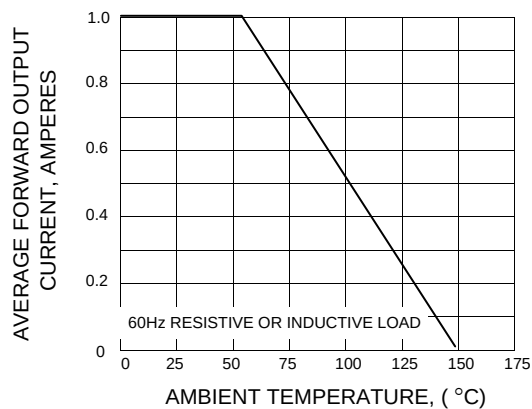


FIG.3 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

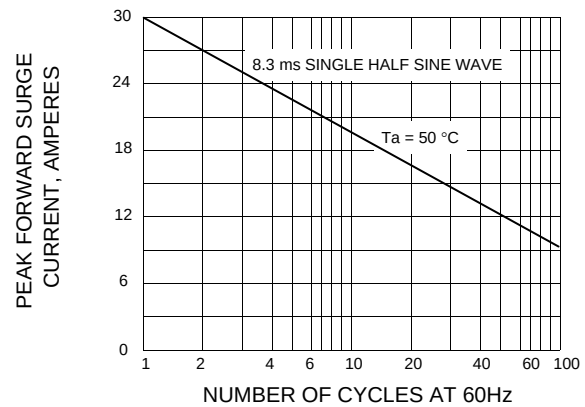


FIG.4 - TYPICAL FORWARD CHARACTERISTICS

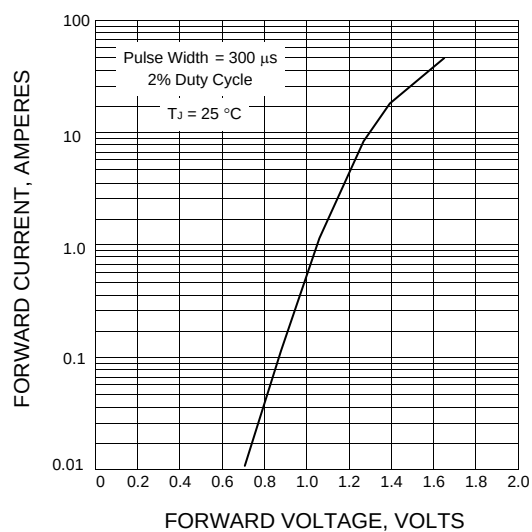


FIG.5 - TYPICAL REVERSE CHARACTERISTICS

